Observation of polaritons in $Bi_2Sr_2CaCu_2O_{8+x}$ single crystals

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The $\rm Bi_2Sr_2CaCu_2O_{8+x}$ high-temperature superconductor represents a natural metamaterial, composed of metallic CuO bilayers sandwiched between ionic BiO planes. Each pair of CuO bilayers forms an atomic-scale Josephson junction. Here we employ the intrinsic Josephson effect for in situ generation and detection of electromagnetic waves in $Bi_2Sr_2CaCu_2O_{8+x}$ single crystals. We observe that electromagnetic waves form polaritons with several transverse optical phonons. This indicates the presence of unscreened polar response in cuprates, which may lead to strong electronphonon interaction. Our technique can provide intense local sources of coherent, monochromatic phonon-polaritons with kW/cm^2 power densities.

Propagation of light in a media is accompanied by electromagnetic (EM) interaction with charged particles. The interaction is strong in polar materials, such as ionic insulators and ferroelectrics. Resonances between light and EM-active collective modes in the media (e.g., optical phonons [\[1\]](#page-3-0), or excitons [\[2,](#page-3-1) [3\]](#page-3-2)) lead to formation of polaritons, half light - half matter particles, with a singular dielectric function

$$
\epsilon_{\rm r}(\omega) = \epsilon_{\infty} + \sum_{j} \frac{\omega_{\rm TO, j}^2 S_j}{\omega_{\rm TO, j}^2 - \omega^2 - i \gamma_j \omega}.
$$
 (1)

It has poles at transverse ω_{TO} and zeroes at longitudinal ω_{LO} optical frequencies. Here S_j and γ_j are oscillator strengths and damping parameters, respectively. Light does not propagate through the media at $\omega_{\text{TO}} < \omega < \omega_{\text{LO}}$ for the same reason that low frequency EM waves do not propagate through metals, namely due to the negative dielectric constant $\text{Re}(\epsilon_r) < 0$. For $\gamma \to 0$ the group velocity of light turns to zero at ω_{TO} . The ability of polaritons to slow down, or even stop and store photons has attracted significant attention in recent years because it may be used in optical metamaterials [\[4,](#page-3-3) [5\]](#page-3-4) and facilitate manipulation of photons in optoelectronics [\[6\]](#page-3-5).

Here we study EM-wave propagation in the layered high temperature superconductor $Bi_2Sr_2CaCu_2O_{8+x}$ (Bi-2212). Superconductivity in cuprates occurs as a result of doping of the parent ionic oxide insulator. Optical spectroscopy has revealed an intermixture of metallic (Drude-type anomaly at $\omega = 0$) and ionic [strong infrared (IR) phonons] properties in cuprates [\[7](#page-3-6)[–9\]](#page-3-7). However, Bi-2212 is not a uniform doped Mott-insulator. It represents a natural atomic superlattice, composed of metallic $CuO₂-Ca-CuO₂$ bilayers sandwiched between ionic SrO-2BiO-SrO planes. Most clearly this was demonstrated by observation of the intrinsic Josephson effect between CuO bilayers [\[10–](#page-3-8)[12\]](#page-3-9). From an optical point of view, Bi-2212 represents a layered photonic crystal [\[13–](#page-3-10)[15\]](#page-3-11) – a multilayer transmission line for EM waves. Therefore, low frequency transverse EM (TEM) waves can propagate along insulating BiO planes [\[16\]](#page-3-12) despite that Bi-2212 is metallic and superconducting. Importantly, the intrinsic Josephson effect allows both in situ generation and detection of TEM waves in the crystal, i.e., the material as such can convert the dc-bias current into high frequency ac-electric field via the quantum mechanical ac-Josephson effect.

We study small mesa structures, fabricated on top of Bi-2212 single crystals using micro/nano-fabrication techniques. We use two batches of crystals: pure, slightly underdoped Bi-2212 with critical temperature $T_c \simeq 82 \text{ K}$, and lead-doped, slightly overdoped $\text{Bi}_{2-y}\text{Pb}_y\text{Sr}_2\text{CaCu}_2\text{O}_{8+x}$ with $T_c \simeq 87-91 \text{K}$. The most noticeable difference between them is in the c-axis critical current density $J_c(4.2 \text{ K}) \simeq 10^3$ and 10^4 A/cm^2 for pure and lead-doped mesas, respectively. Measurements were performed in a gas-flow ⁴He cryostat in a temperature range down to 1.6 K and magnetic field H up to 17 T. Samples were mounted on a rotatable sample holder. Accurate alignment of the field parallel to CuO planes was needed to avoid intrusion of Abrikosov vortices in intense magnetic fields. For alignment we used the procedure developed in Ref. [\[12\]](#page-3-9), which facilitates alignment with an accuracy better than 0.02◦ . Details of sample fabrication and measurements can be found in Refs. [\[12\]](#page-3-9) and [\[16\]](#page-3-12).

The inset of Fig. [1](#page-1-0) shows current-voltage $(I-V)$ characteristics of a lead-doped mesa $(M1, 1.3 \times 1.9 \,\mu m^2)$. Periodic branches are due to one-by-one switching of junctions from the superconducting to the quasiparticle (QP) state [\[10,](#page-3-8) [17\]](#page-3-13). Additional small sub-branches are seen at every QP branch. They represent resonances between the ac-Josephson oscillations in intrinsic junctions and c-axis LO phonons [\[18](#page-3-14)[–21\]](#page-3-15). Figure [1](#page-1-0) shows temperature dependence of the first QP branch for the same mesa. Unlike the superconducting gap and QP resistance, which decrease with increasing T [\[17\]](#page-3-13), the voltages of phonon resonances remain independent of T and correspond to frequencies of IR and Raman active c-axis phonons [\[7,](#page-3-6) [8,](#page-3-16) [22\]](#page-3-17). Their identification is provided in Table [I.](#page-1-1)

The amplitude of phonon resonances is proportional to $J_{\rm c}^2$ [\[21\]](#page-3-15). Since $J_{\rm c}$ for our lead-doped crystals is about ten times larger than for pure Bi-2212 crystals, phonon resonances in the lead-doped mesas are greatly enhanced. For analysis of resonances in pure Bi-2212 we have to look on dI/dV characteristics [\[20\]](#page-3-18). Similarly, resonances are strongly suppressed by a moderate c-axis magnetic

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FIG. 1. Temperature dependence of the first QP branch for the lead-doped mesa M1 in zero magnetic field. It is seen that phonon frequencies are T-independent. The inset shows QP branches in the $I-V$ of the same mesa at $T = 1.6$ K. Resonances with LO phonons are seen at every QP branch.

field. This is caused by penetration of Abrikosov pancake vortices in CuO planes, which suppress supercon-ductivity [\[23\]](#page-3-19) and J_c . In contrast, in-plane magnetic field up to 17 T is not affecting superconductivity and J_c at $T \ll T_c$ due to the extremely large anisotropy of Bi-2212. The apparent Fraunhofer modulation of the c-axis critical current in this case [\[12\]](#page-3-9) is caused by interference of opposite supercurrents, circulating in Josephson fluxons, with unsuppressed amplitude J_c .

At sufficiently large magnetic field, fluxons form a regular lattice in the mesa [\[12\]](#page-3-9). The number of fluxons per junction is given by the ratio Φ/Φ_0 , where $\Phi = HLs$ is the flux per junction, L is the junction length, $s \approx 1.5$ nm is the stacking periodicity of intrinsic junctions, and Φ_0 is the flux quantum. The c-axis bias current exerts a Lorentz force and causes unidirectional fluxon motion. This leads to appearance of an additional flux-flow branch in the I-V curve, with the voltage per junction $V_{FF} = u_{FF}Hs$, where u_{FF} is the fluxon velocity. Periodic collision of fluxons with the edge of the mesa leads to flux-flow oscillations [\[16\]](#page-3-12). Produced EM waves are partly emitted and partly reflected back into the junctions. The latter start to travel as TEM waves in the multilayered transmission line formed by the mesa, get reflected at the opposite edge, and continue bouncing until decay.

Figure [2](#page-1-2) shows flux-flow part of the I-V for a leaddoped mesa $(M2, 1.2 \times 2 \mu m^2)$, measured during continuous sweep of the in-plane magnetic field from 4.2 to 4.4 T. The flux-flow voltage grows gradually with H . Bouncing TEM waves can be explicitly visualized at geometrical resonance conditions, corresponding to formation of

#	V	ω_{LO}	type	symmetry	assignment
	(mV)	$\rm (cm^{-1})$			
1	6.0	97	IR.	A_{2u}	Bi':Cu1CaSr
$\overline{2}$	7.8	126	Raman	A_{1g}	Cu1Sr
3	10.5	169	IR.	A_{2n}	Sr:Cu1'
4	11.2	181	Raman	A_{1g}	Sr:Cu1'
5	14.5	234	IR.	A_{2n}	Ca:Sr'
6	20.4	329	IR.	A_{2n}	0301
	22.8	368	IR.	A_{2n}	$O1$:CaO3
8	25.5	411	Raman	A_{1g}	O1:Sr'

TABLE I. Identification of LO phonon resonances at zero field, marked in Fig.1 (following Ref. [\[8\]](#page-3-16)).

FIG. 2. Flux-flow part of the I-V for the lead-doped mesa M2, measured during continuous sweep of the in-plane magnetic field from 4.2 to 4.4 T. The inset shows a series of Fiske steps, caused by formation of standing waves inside the mesa. It demonstrates the Josephson flux-flow mechanism of TEM wave generation in our experiment.

standing waves in the mesa. They are seen as a series of Fiske steps on the flux-flow branch [\[16\]](#page-3-12). We note that those TEM waves are photon (or surface plasmon [\[6\]](#page-3-5)) like, because they have a linear dispersion relation at low frequencies. This leads to equidistance of Fiske steps [\[16\]](#page-3-12). The inset in Fig. [2](#page-1-2) demonstrates the Fiske step sequence, corresponding to out-of-phase oscillations in neighboring junctions with one node per junction [\[16\]](#page-3-12). The corresponding slowest speed of light $c_N \simeq 3.9 \times 10^5 \,\mathrm{m/s}$ is almost one thousand times slower than the speed of light in vacuum – not because of the extraordinary large ϵ_r , but due to an extraordinary large kinetic inductance of the atomically thin intrinsic junctions.

The strongest geometrical resonance occurs at the

FIG. 3. A set of I-V curves for the lead-doped mesa M3 at different in-plane magnetic fields and $T = 1.6$ K. The curves are offset vertically for clarity. Development of the velocity-matching flux-flow resonance (circles) and higher flux-flow/phonon resonances (squares, rhombuses and triangles) is seen. With increasing H voltages of flux-flow-phonon resonances first increase and then saturate when the ac-Josephson frequency is approaching the next TO phonon frequency (marked by vertical lines).

velocity-matching condition, when u_{FF} is equal to the phase velocity of TEM waves [\[16\]](#page-3-12). In this case waves are synchronized with the fluxon chain and the wave length is equal to the separation between fluxons. The corresponding TEM wave number is

$$
k = 2\pi H s/\Phi_0.
$$
 (2)

It can be easily tuned by changing H . In experiment the velocity matching resonance is seen as a sharp upturn (maximum in dI/dV) at the top of the flux-flow branch. The corresponding frequency is given by the ac-Josephson relation

$$
\omega = 2\pi V_{\rm FF}^*/\Phi_0,\tag{3}
$$

where $V_{\rm FF}^*$ is the measured maximum flux-flow voltage per junction. Eqs. [\(2](#page-2-0)[,3\)](#page-2-1) provide the basis for analysis of the dispersion relation in this work.

Figure [3](#page-2-2) shows I vs. V per junction at different in-plane magnetic fields for a lead-doped mesa (M3, $0.9 \times 1.3 \,\mu\text{m}^2$ with $N = 11$ junctions. The velocitymatching flux-flow resonance is marked by circles. It is moving to higher voltages with increasing H and eventually saturates upon approaching the voltage of phonon $#2$ in Table [I.](#page-1-1) Above it we observe a series of additional, remarkably strong resonances. The first three are marked by squares, rhombuses and triangles, respectively. They develop gradually out of one of the LO phonon resonances at $H = 0$, grow in amplitude and move to higher voltages with increasing field. Finally, they saturate at high fields when the voltage is approaching the next phonon resonance, as indicated by vertical lines. Those resonances can not be associated with bare LO phonons, which are field independent, but represent a combination of flux-flow and phonon resonances. Each series have N sub-branches with voltages $V_j = (N - j)V_{\text{FF}} + jV_{\text{R}}$, $(j = 1, 2, \dots N)$ due to one-by-one switching of N junctions from the flux-flow V_{FF} to the resonance state V_{R} . $N = 11$ sub-branches in each series can be distinguished at $H = 17$ T in Fig. [3.](#page-2-2) The last sub-branch in each series represents the flux-flow/phonon resonance frequency.

Figure [4](#page-3-20) presents our main result: voltage per junction of flux-flow/phonon resonances vs. H , which are translated into the dispersion relation ω vs. k via Eqs. $(2,3)$ $(2,3)$. Figure $4(a)$ shows the dispersion relation for the mesa M3. The lowest dispersion branch corresponds to the regular flux-flow branch, indicated by circles in Fig. [3.](#page-2-2) It is roughly linear at low k , corresponding to a constant speed of light $\simeq 4 \times 10^5$ m/s close to the out-ofphase TEM velocity, obtained independently from analy-sis of Fiske steps [\[16\]](#page-3-12). At larger k $(H > 12$ T) we observe a clear saturation with the group velocity $d\omega/dk \rightarrow 0$ when the flux-flow frequency is approaching the lowest Raman active phonon $#2$ in Table [I.](#page-1-1) Higher dispersion branches correspond to flux-flow/phonon resonances, indicated in Fig. [3.](#page-2-2) They start flatly from a certain LO phonon frequency at $k = 0$, grow at intermediate k and saturate again at large k , when the frequency approaches the next phonon (indicated by horizontal lines). Figure [4\(](#page-3-20)b) demonstrates a similar behavior of mesa M1, which is slightly more overdoped and has about 30% larger J_c . Figure [4\(](#page-3-20)c) shows the dispersion relation obtained for a pure Bi-2212 mesa. Since phonon resonances are much weaker here due to smaller J_c , we are able to trace interaction only with the two lowest phonons.

The obtained results are in excellent agreement with theoretical prediction by Preis et al. [\[24\]](#page-3-21) on the mutual influence of flux-flow and phonon resonances in Josephson junctions with ionic barriers. Interaction of oscillating electric field with IR and Raman active phonons leads to formation of polaritons, which slow down the group velocity of light to zero $d\omega/dk \to 0$ at $\omega \to \omega_{\text{TO}}$ and prohibit propagation of TEM waves and flux-flow at voltages $\Phi_0 \omega_{\text{TO}}/2\pi < V_{\text{FF}} < \Phi_0 \omega_{\text{LO}}/2\pi$. This leads to the observed stratification of $I-V$ characteristics in Fig. [3.](#page-2-2) Our data is well described by the polaritonic dispersion relation of Eq. (1) , as shown in Fig. $4(d)$.

Observation of strong polariton-like interaction of TEM waves with IR and Raman active c-axis phonons highlight the unusual natural metamaterial-type elec-

FIG. 4. Obtained TEM-wave dispersion relations for (a) mesa M3, (b) mesa M1, and (c) a pure Bi-2212 mesa. It is seen that the dispersion relation is linear at low frequencies (constant speed of light), but saturate (zero group velocity) whenever the frequency is approaching the phonon frequency, indicating formation of polaritons. Panel (d) shows simulated polaritonic dispersion relation from Eq. [\(1\)](#page-0-1). Horizontal lines represent all observed LO frequencies.

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tronic structure of cuprates, in which two-dimensional metallic CuO layers are sandwiched between ionic layers. The combination of long range Coulomb interaction in two-dimensional metallic layers with polar media around them, may lead to an unusually strong electron-phonon interaction [\[25](#page-3-22)[–29\]](#page-4-0). This is import for understanding of the puzzling phenomenon of high temperature superconductivity.

The maximum power, pumped into phonon-polariton emission can be explicitly estimated from the amplitude of flux-flow/phonon resonances in Fig. 3: $P = \Delta IV_R \sim$ $10 \,\mu\text{W}$, where $\Delta I \sim 100 \,\mu\text{A}$ is the maximum resonance amplitude and $V_R \sim 100 \,\mathrm{mV}$ is the total voltage at the resonance. This corresponds to $kW/cm²$ emission power density. It can be further enhanced in a coherent (cascade) manner using mesas with larger amount of stacked junctions [\[30\]](#page-4-1). Thus, our results demonstrate that voltage biased Bi-2212 mesas act as compact and intense source of coherent, monochromatic phonon-polaritons (or surface plasmons) with power densities ~kW/cm². Such local surface-plasmon sources are on demand in a rapidly growing area of optoelectronics [\[4](#page-3-3)[–6\]](#page-3-5). The discovered phenomenon may also be used for creation of a THz phonon laser [\[30\]](#page-4-1).

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